DOI: 10.5515/JKIEES.2011.11.2.076

# Dual-Band Negative Group Delay Circuit Using $\lambda/4$ Composite Right/Left-Handed Short Stubs

Heungjae Choi<sup>1</sup> · Taesu Mun<sup>1</sup> · Yongchae Jeong<sup>1</sup> · Jongsik Lim<sup>2</sup> · Soon-Young Eom<sup>3</sup> · Young-Bae Jung<sup>4</sup>

#### **Abstract**

In this paper, a novel design for a dual-band negative group delay circuit (NGDC) is proposed. Composite right/left-handed (CRLH)  $\lambda/4$  short stubs are employed as a dual-band resonator. A CRLH  $\lambda/4$  short stub is composed of a typical transmission line element as the right-handed component and a high-pass lumped element section as the left-handed component. It is possible to simultaneously obtain open impedances at two separate frequencies by the combination of distinctive phase responses of the right/left-handed components. Negative group delay (NGD) can be obtained at two frequencies by using dual-band characteristics of the CRLH stub. In order to achieve a bandwidth extension, the proposed structure consists of a two-stage dual-band NGDC with different center frequencies connected in a cascade. According to the experiment performed, with wide-band code division multiple access (WCDMA) and world-wide interoperability for microwave access (WiMAX), NGDs of  $-3.0\pm0.4$  ns and  $-3.1\pm0.5$  ns are obtained at 2.12  $\sim$ 2.16 GHz and  $3.46 \sim 3.54$  GHz, respectively.

Key words: Composite Right/Left-Handed, Dual-Band, Negative Group Delay, WCDMA, WiMAX.

## I. Introduction

In the process of the rapid evolution into a ubiquitous communication environment, the demands for multi-band mobile/base-station devices capable of adapting to multiple wireless communication platforms have increased considerably [1], [2].

Recently, some interesting studies on the negative group delay (NGD) concept have led to its experimental validation through the realization of its electronic circuit. In a specific and narrow frequency band of signal attenuation or in an anomalous dispersion, the group velocity is observed to be greater than that of c, the speed of light in a vacuum, or even to be negative. A fasterthan-c phenomenon was defined as the superluminal group velocity, and negative group velocity is also referred to as NGD. Experimental validations of the theoretical analysis regarding these phenomena have been presented in previous studies [3] $\sim$ [5]. In the early stages, the NGD concept had little use in practical radio frequency (RF) system design because of its extremely narrow bandwidth and poor input/output return loss. Researchers have been investigating some topologies for the NGD and have found some useful practical applications in RF circuit design [6]~[14]. General synthesis equations and the planar circuit implementation technique with good input/output return loss were proposed in [9], [10]. A negative group delay circuit (NGDC) has been successfully employed in a signal cancellation loop to improve the time advance property [11], and to an analog feed-forward amplifier in a WCDMA band to improve the overall system efficiency [12]. NGDC was also adapted to the analog feedback linearization topology to reduce the feed-back time (the propagation time required for a signal coupled from the power amplifier output terminal that is to be transmitted through several signal adjusting devices before being injected into the input terminal) and to increase the cancellation bandwidth [13]. Dualband NGD topology was proposed in [14], but the NGD could only be obtained at the specific frequencies without bandwidth flatness.

The CRLH transmission line (TL), which consists of a left-handed TL (LH TL) and the typical right-handed TL (RH TL) was proposed in [15], [16]. The equivalent lumped element circuit of the LH TL shows positive phase response (phase lead). However, the RH TL has a negative phase response (phase lag). These have been applied to the design of a dual-band  $\lambda/4$  short stub, in which the phase response of the CRLH TL is manipulated to yield the electrical lengths of odd multiple of  $\pm 90^{\circ}$ , at two arbitrary frequencies.

Based on the results obtained in [1] and  $[9] \sim [16]$ , we

Manuscript received December 16, 2010; revised March 8, 2011. (ID No. 20101216-040J)

<sup>&</sup>lt;sup>1</sup>Department of Electronics and Information Engineering, Chonbuk National University, Jeonju, Korea.

<sup>&</sup>lt;sup>2</sup>Department of Electrical and Communication Engineering, Soonchunhyang University, Asan, Korea.

<sup>&</sup>lt;sup>3</sup>Antenna Technology Research Team, Electronics and Telecommunications Research Institute (ETRI), Daejeon, Korea.

<sup>&</sup>lt;sup>4</sup>Division of Electric, Electronic and Control Engineering, Hanbat National University, Daejeon, Korea.

Corresponding Author: Yongchae Jeong (e-mail: ycjeong@jbnu.ac.kr)

set our goal to extend the application of NGDC to dual-band operation for WCDMA and a WiMAX base-station. First, we will explain the principals of NGD and  $\lambda/4$  CRLH short stub. Second, the proposed circuit topology and operation principles are also described in detail. Finally, a comparison of the 1-stage and 2-stage dual-band NGDCs in relation to bandwidth flatness and commercial applicability is provided.

## II. Theory and Simulation

In the medium of a refractive index  $n(\omega)$ , the dispersion relation can be written as [5]:

$$\kappa = \frac{\omega n}{c} \,, \tag{1}$$

where k is the wave number and c is the speed of light. The group velocity  $(v_g)$ , meaning the speed of the envelope signal, is then given by:

$$v_{g} = \frac{c}{n + \omega \operatorname{Re}[dn/d\omega]} . \tag{2}$$

From the above equation, it can be inferred that if the refractive index decreases rapidly according to the frequency, the group velocity can become negative. This event does happen near an absorption line or in media with signal attenuation, where anomalous wave propagation effects can occur [5]. Typically, in an RF circuit design based on a dielectric laminate, we cannot control the refractive index of the given material. But it is possible to obtain an NGD through intentional resistive signal attenuation. Additionally, the attenuation can be easily compensated with a small signal gain amplifier, without reducing total NGD [10].

The main goal of this work is to design a dual-band NGDC for the WCDMA downlink band (2.14±0.02 GHz) and the WiMAX band (3.50±0.04 GHz). A circuit diagram of the proposed dual-band NGDC is provided in Fig. 1. The proposed circuit consists of a broadband 3 dB 90° hybrid coupler to fully cover the two frequencies (2.14~3.5 GHz) [17], and a termination resistor  $R_{RP}$  that is loaded with a CRLH  $\lambda/4$  short stub for dual-band operation. To increase the bandwidth flatness for a practical application, 2-stages of dual-band NGDCs with different frequencies of operation can be cascaded. If we assume  $f_1$ ,  $f_2$ ,  $f_3$ , and  $f_4$  as 2.12, 2.16, 3.46, and 3.54 GHz, respectively, unit #1 should have a dual-band operation for  $f_1$  and  $f_3$ , and unit #2 should have a dual-band operation for  $f_2$  and  $f_4$ , for example. The cascading of these two units produces a flat bandwidth in terms of the insertion loss and the NGD. In this case, signal attenuation is also increased. Therefore, careful trade-

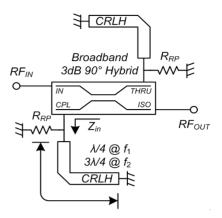


Fig. 1. Circuit diagram of the proposed 1-stage dual-band negative group delay circuit (NGDC).

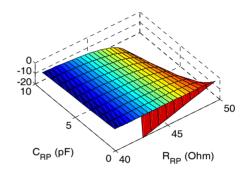


Fig. 2. Calculated group delay according to  $R_{RP}$  from 40 to 50  $\Omega$ , and CRP from 0 to 10 pF with 2 pF steps.

off between the NGD and insertion loss should be considered.

The condition to obtain the NGD in a reflective parallel (RP) NGDC can be expressed by the following equation [12]:

$$\tau = \frac{-d\Phi_{in}}{d\omega}\bigg|_{\omega = \omega_1, \omega_2} = \frac{4R_{RP}^2 C_{RP} Z_0}{R_{RP}^2 - Z_0^2} , \qquad (3)$$

where  $\tau$  is the group delay,  $\Phi_{in}$  is the phase of the input impedance ( $Z_{IN}$ ) at the coupling and the through port of the 90° hybrid coupler,  $\omega_1$  and  $\omega_2$  are the resonant frequencies of the CRLH  $\lambda/4$  short stub, which has dual-band characteristics,  $C_{RP}$  is the total equivalent capacitance of the lumped element equivalent circuit of the CRLH  $\lambda/4$  short stub, and  $Z_0$  is the termination impedance of the broadband 90° hybrid coupler, which is 50  $\Omega$  in this case. If  $\tau$  is to be negative,  $R_{RP}$  needs to be smaller than 50  $\Omega$ . The NGD is proportional to  $C_{RP}$  and  $R_{RP}$ , as shown in Fig. 2. In Fig. 1, the coupling (CPL) and through (THRU) port of the 90° hybrid coupler needs to be terminated with  $R_{RP}$  at the resonant frequency, which implies that the input impedance of the  $\lambda/4$  stub needs to be open at the desired frequen-

cies. This operation can be achieved by adapting the CRLH transmission line.

The CRLH  $\lambda/4$  short stub, which is a combination of the conventional right-handed (RH) and the left-handed (LH) transmission line, exhibits a dual-band response [15], [16]. The phase response of a CRLH structure is expressed as (4):

$$\phi_C = \phi_R + \phi_L \approx -N\omega\sqrt{L_R C_R} + \frac{N}{\omega\sqrt{L_L C_L}} , \qquad (4)$$

where  $\phi_R$ ,  $\phi_L$ , and  $\phi_C$  are the electrical lengths of RH, LH, and CRLH component, respectively, and N denotes the number of stages, and  $\omega$  is the angular frequency.  $L_R$  and  $C_R$  denote the component values of the RH component, and  $L_L$  and  $C_L$  denote the component values of the LH component. Given N, two frequencies of operation  $(f_1, f_2)$ , the desired phase responses at these frequencies  $(\phi_1, \phi_2)$ , which are  $-90^\circ$  and  $-270^\circ$  in this case, and the characteristic impedance of the CRLH line  $(Z_0)$ , which is typically  $50 \ \Omega$ , mean that the component values of the CRLH line can be obtained from the following equations:

$$L_{R} = \frac{Z_{0} \left( \frac{\phi_{1}}{f_{2}} - \frac{\phi_{2}}{f_{1}} \right)}{2\pi N \left( \frac{f_{2}}{f_{1}} - \frac{f_{1}}{f_{2}} \right)}$$
(5)

$$C_{R} = \frac{\left(\frac{\phi_{1}}{f_{2}} - \frac{\phi_{2}}{f_{1}}\right)}{2\pi N Z_{0} \left(\frac{f_{2}}{f_{1}} - \frac{f_{1}}{f_{2}}\right)}$$
(6)

$$L_{L} = \frac{Z_{0}N\left(\frac{f_{2}}{f_{1}} - \frac{f_{1}}{f_{2}}\right)}{2\pi(\phi_{1}f_{2} - \phi_{2}f_{1})}$$
(7)

$$C_{L} = \frac{N\left(\frac{f_{2}}{f_{1}} - \frac{f_{1}}{f_{2}}\right)}{2\pi Z_{0}(\phi_{1}f_{2} - \phi_{2}f_{1})}$$
(8)

$$Z_0 = \sqrt{\frac{L_R}{C_R}} = \sqrt{\frac{L_L}{C_L}} \quad . \tag{9}$$

Fig. 3 shows the phase response of CRLH dual-band  $\lambda/4$  and RH  $\lambda/4$  transmission line. Due to the positive phase response of the LH component, the CRLH transmission line demonstrates a higher phase slope than the RH line for a fixed electrical length. In other words, the electrical lengths of the odd multiple of  $-90^{\circ}$  ( $\lambda/4$  and  $3\lambda/4$ ) are obtainable at odd harmonic frequencies in the case of the RH line. However, in the CRLH case, the

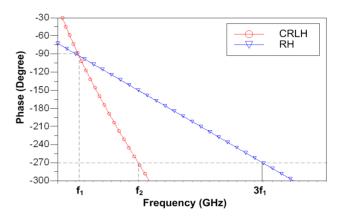


Fig. 3. Simulated phase response of the composite right/left-handed (CRLH) dual-band  $\lambda/4$  and RH  $\lambda/4$  transmission line.

frequency with the  $3 \lambda/4$  wavelength, which is the second desired frequency, can be controlled by adjusting the number of the stages of the LH unit cell (N) and the combined parameter values ( $C_L$ ,  $L_L$ ) together with the electrical length of the RH lines ( $\theta_{RH} = \theta_1 + \theta_2$ ) within the range of  $1 < f_2/f_1 < 3$ .

Fig. 4 shows the schematic of the CRLH dual-band  $\lambda/4$  short stub, and Fig. 5 shows the simulation and measurement results. The number of unit cells (N) for 2.14 GHz and 3.5 GHz is calculated as 3. It is validated through circuit simulation using Agilent's ADS2009 and measurement. The required circuit parameters are as follows:  $C_L$ =2.1 pF,  $2C_L$ =4.2 pF,  $L_L$ =30°/133  $\Omega$  (short stub), and  $|\theta_{RH}|$ =193° for circuit simulation,  $C_L$ =1.8 pF,  $2C_L$ =3.0 pF,  $L_L$ =36°/133  $\Omega$  (short stub), and  $|\theta_{RH}|$ =183° for measurement. Simulated and measured results were consistent, except for a slight resistance difference due to the limited quality factor of the real-world components.

### III. Experiment

The broadband 3 dB 90° hybrid coupler has been employed as a hybrid coupler to cover 2.14 GHz and 3.5

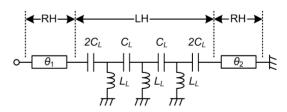


Fig. 4. The schematic of the CRLH  $\lambda/4$  short stub for N=3. Component values:  $C_L=2.1$  pF,  $2C_L=4.2$  pF,  $L_L=30^\circ/133$   $\Omega$  (short stub), and  $|\theta_{RH}|=193^\circ$  for circuit simulation,  $C_L=1.8$  pF,  $2C_L=3.0$  pF,  $L_L=36^\circ/133$   $\Omega$  (short stub), and  $|\theta_{RH}|=183^\circ$  for measurement.

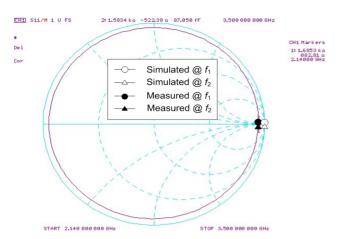


Fig. 5. Simulated and measured results of the CRLH dual-band  $\lambda/4$  short stub for 2.14 GHz and 3.5 GHz.

GHz at the same time. Due to the extremely narrow coupling gap in the central coupling element, caused by too small odd impedance, the design of a 3 dB planar multi-section coupler with a broad bandwidth is a tough goal. Based on the design method proposed in [17], the broadband 3 dB 90° hybrid coupler, which covers  $f_1$ = 2.14 GHz and  $f_2$ =3.5 GHz was designed using the vertically installed planar (VIP) structure to increase the coupling area at the central coupling element.

Fig. 6 shows a photograph of the fabricated broadband 3 dB 90° hybrid coupler, and the measured results compared with the electro-magnetic (EM) wave simulation are shown in Fig. 7. The measured magnitudes of coupling and through ports are  $-3.10\pm0.2$  dB and  $-3.18\pm0.01$  dB, respectively. The maximum return loss is higher than 30 dB for 2.14/3.5 GHz. A dual-band NGDC employing the CRLH  $\lambda/4$  stub and the broadband 3 dB 90° hybrid coupler is designed and implemented according to the proposed design method, and is fabricated with a microstrip line.

In Fig. 8, we compare the simulated results of the

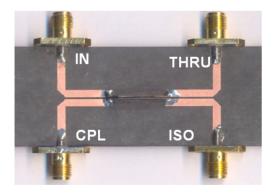


Fig. 6. Photograph of the fabricated broadband 3 dB 90° hybrid with a vertically installed planar structure.

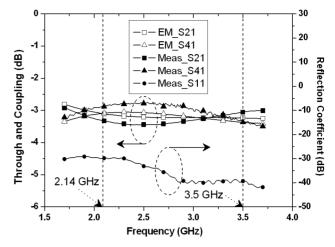


Fig. 7. Comparison of EM simulation and measurement.

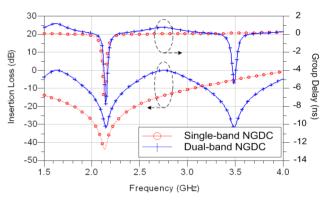
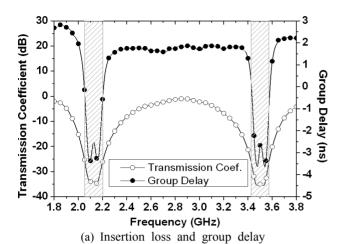


Fig. 8. Simulated group delay and reflection coefficient of the 1-stage single-band [10] and dual-band NGDC.

1-stage single-band NGDC with  $\lambda/4$  RH short stubs, from [10], and the dual-band NGDC, from this work. The dual-band NGDC shows NGDs of around -7 ns and -5 ns at 2.14 GHz and 3.5 GHz, respectively. The time difference of 2 ns between the two frequencies was due to the fact that the termination impedances of the designed broadband hybrid coupler are not exactly 50  $\Omega$ . When the termination impedance of the 3 dB hybrid coupler is not 50  $\Omega$ , the resulting NGD varies from the desired value, as expected in (3).

Fig. 9 shows the measured 2-stage dual-band NGDC. In unit #1,  $C_{COMP}$ =0.8 pF,  $C_L$ =1.8 pF,  $2C_L$ =3.0 pF,  $|\Theta|$  RH|=188°,  $L_L$ =35°/133  $\Omega$  (short stub) were used in practical realization to obtain the dual-band operation at  $f_1$  and  $f_3$ . In unit #2,  $C_{COMP}$ =0.9 pF,  $C_L$ =1.7 pF,  $2C_L$ =3.4 pF,  $|\Theta_{RH}|$ =181°,  $L_L$ =33°/133  $\Omega$  (short stub) were used to obtain the dual-band operation at  $f_2$  and  $f_4$ . For both units, an  $R_{RP}$  of 47/500  $\Omega$  were used. The insertion loss and group delay are shown in Fig. 9(a), and the phase and return loss are presented in Fig. 9(b). The high-lighted areas show the NGD regions. The NGD of -3.0



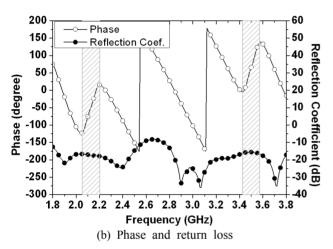


Fig. 9. The measured results of the 2-stage dual-band NGDC. Phase slopes are inverted in the highlighted dual-band NGD regions.

 $\pm 0.4$  ns and  $-3.1\pm 0.5$  ns were obtained at  $2.12\sim 2.16$  GHz and  $3.46\sim 3.54$  GHz, respectively. The magnitude of the flatness for each band was measured as  $-34.2\pm 0.5$  dB and  $-34.9\pm 0.7$  dB, respectively. The maximum return loss was -17 dB. When compared to the reference results presented in [14], the 2-stage dual-band NGDC had a wider bandwidth, showing practical applicability. According to the results from [10], a small signal general purpose gain amplifier with small power consumption (<0.5 W) and with small additional group delay (<0.2 ns) can be used to compensate for the insertion loss of around 35 dB. For high power applications over a few tens of watts, this extra power consumption has a slight effect on the total system efficiency.

In the NGD region, the slope of the phase is observed to be positive, implying that the group velocity is negative. Negative group velocity means that the direction of envelope propagation is opposite to the direction of the signal propagation. This inverted phase slope can

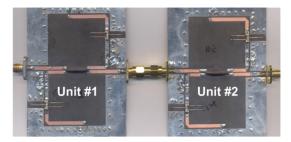


Fig. 10. A photograph of the fabricated 2-stage dual-band NGDC

be used to cancel out or control the negative phase slope (or positive GD) of a conventional circuit, consequently achieving a zero phase slope (therefore smaller or even zero GD). For example, in case of intermodulation distortion of the cancellation loop in an analog feedforward amplifier, NGDC can be used to eliminate a lossy delay element and increase the system efficiency [12]. Fig. 10 shows the photograph of the fabricated 2-stage dual-band NGDC. The total size is 140×70 mm<sup>2</sup>.

### IV. Conclusion

In this paper, we propose the novel design and implementation of a 2-stage dual-band NGDC using a composite right/left-handed transmission line. The importance of the proposed work lies in the dual-band design for the interesting NGD property. The proposed circuit is expected to be applicable to WCDMA and Wi-MAX base-station applications given its ability to reduce lossy output delay elements and improve the efficiency of the systems through the dual-band positive phase response characteristics.

# References

- H. Choi, Y. Jeong, J. S. Kenney, and C. D. Kim, "Dual-band feedforward linear power amplifier for digital cellular and IMT-2000 base-station," *Micro*wave Optical Technol. Lett., vol. 51, no. 4, Apr. 2009.
- [2] M. R. Ghajar, S. Boumaiza, "Concurrent dual band 2.4/3.5GHz fully integrated power amplifier in 0.13 um CMOS technology," in *Proc. 39th European Microwave Conf.*, pp. 1728-1731, Sep. 2009.
- [3] D. Solli, R. Y. Chiao, "Superluminal effects and negative delays in electronics, and their applications," *Physical Review E*, issue 5, Nov. 2002.
- [4] L. J. Wang, A. Kuzmich, and A. Dogariu, "Gain-assisted superluminal light propagation," *Nature 406*, pp. 277-279, Jun. 2000.
- [5] L. Brillouin, A. Sommerfeld, Wave Propagation and

- *Group Velocity*, Academic Press Network, pp. 113-137, 1960.
- [6] S. Lucyszyn, I. D. Robertson, "Analog reflection topology building blocks for adaptive microwave signal processing applications," *IEEE Trans. Microwave Theory and Tech.*, vol. MTT-43, no. 3, pp. 601-661, Mar. 1995.
- [7] H. Noto, K. Yamauchi, M. Nakayama, and Y. Isota, "Negative group delay circuit for feed-forward amplifier," in *IEEE MTT-S Int. Microwave Symp. Dig.*, pp. 1103-1106, Jun. 2007.
- [8] B. Ravelo, A. Perennec, and M. Le Roy, "Synthesis of broadband negative group delay active circuits," in *IEEE MTT-S Int. Microwave Symp. Dig.*, pp. 2177-2180, Jun. 2007.
- [9] H. Choi, K. Song, C. D. Kim, and Y. Jeong, "Synthesis of negative group delay time circuit," in *Asia-Pacific Microw. Conf. Dig.*, pp. B5-08, 2008.
- [10] H. Choi, Y. Kim, Y. Jeong, and C. D. Kim, "Synthesis of reflection type negative group delay circuit using transmission line resonator," in *Proc.* 39th European Microwave Conf., pp. 902-905, Sep. 2009
- [11] Y. Jeong, H. Choi, and C. D. Kim, "Experimental verification for time advancement of negative group delay in RF electronics circuits," *Electron. Lett.*, vol. 46, no. 4, pp. 306-307, Feb. 2010.
- [12] H. Choi, Y. Jeong, C. D. Kim, and J. S. Kenney, "Efficiency enhancement of feedforward amplifiers

- by employing a negative group-delay circuit," *IEEE Trans. Microwave Theory and Tech.*, vol. 58, no. 5, pp. 1116-1125, May 2010.
- [13] H. Choi, Y. Jeong, C. D. Kim, and J. S. Kenney, "Bandwidth enhancement of an analog feedback amplifier by employing a negative group delay circuit," *Progress in Electromagnetics Research*, vol. 105, pp. 253-272, 2010.
- [14] H. Choi, S. Shim, Y. Jeong, J. Lim, C. D. Kim, S. Y. Eom, and Y. B. Jung, "2.14/3.5 GHz novel dual-band negative group delay circuit design based on composite right/left-handed transmission line," in *Proc. 40th European Microwave Conf.*, pp. 441-444, Sep. 2010.
- [15] C. Caloz, A. Sanada, and T. Itoh, "A novel composite right/left-handed coupled-line directional coupler with arbitrary coupling level and broad bandwidth," *IEEE Trans. on Microwave Theory and Tech.*, vol. 52, pp. 980-992, Mar. 2004.
- [16] P. Chi, T. Itoh, "Miniaturized dual-band directional couplers using composite right/left-handed transmission structures and their applications in beam pattern diversity systems", *IEEE Trans. on Microwave Theory and Tech.*, vol. MTT-57, no. 5, pp. 1207-1215, May 2009.
- [17] I. S. Kim, C. S. Lee, "A study on broadband hybrid design using vertically installed planar circuit with partially removed ground plane," *Journal of KIEES*, vol. 16, no. 7, pp. 661-670, Jul. 2005.

## Heungjae Choi



received the B.S. and M.S. degrees in electriones and information engineering from Chonbuk National University, Jeonju, Korea, in 2004 and 2006, respectively. His master's research focused on the design of dual-band linear power amplifier for base-station application. He is now working toward his Ph.D. Degree. His research in-

terests include broadband linearization and high-efficiency RF PAs, and recently negative group delay and its RF and electronic circuit application.

# Taesu Mun



received the B.S. degree from Chonbuk National University, Jeonju, Korea in 2011 in Division of Electronics and Information Engineering. From 2011, he is studying in master's course in Division of Electronics and Information Engineering, Chonbuk National University, Jeonju, Korea. Mr. Moon is currently conduc-

ting research in the area of RF power amplifier design.

## Yongchae Jeong



received the B.S., M.S. and Ph.D. degrees from Sogang University, Seoul, Korea, in 1989, 1991, and 1996, respectively all in electronic engineering. From 1991 to 1998, he was a Senior Engineer in information & communication division of Samsung Electronics. From 1998, he has joined as a faculty in the Division of Electronics

and Information Engineering, Chonbuk National University. From 2006-2008, he visited Georgia Institute of Technology as a visiting research professor. Now he is a Vice Dean of College of Engineering in Chonbuk National University. He is a member of the Korean Institute of Electromagnetic Engineering and Science (KIEES). He currently conducts research in the area of microwave devices, base-station amplifiers, linearizing technology, and RFIC design.

### Soon-Young Eom



was born in Gangwon-do, Korea, on May 2, 1964. He received the B.S. and M.S. degrees in electronic engineering from Yonsei University, Seoul, Korea, in 1988 and 1990 respectively. Since 1990, he has worked at Electronics and Telecommunications Research Institute (ETRI), Daejeon, Korea, as a principal member of re-

search staff. From 1991 to 1993, he participated in the joint project with Alenia Spazio S.P.A in Italy, for developing the very small aperture terminal (VSAT) system. With the study on flat-topped radiation pattern using a multi-layered disk array structure, he received the Ph.D degree in electronic engineering from Yonsei University, Seoul, Korea, in 2003. From 1996 to 2005, he took part in developing many mobile active phased array antenna systems for direct broadcasting satellite (DBS) reception and satellite communications. He is now involved to develop the reconfigurable antenna and its system application technology. His research interests include active phased array antenna systems, microwave circuits and systems, and advanced mobile base station antenna systems.

Jongsik Lim



received the B.S. and M.S. degrees in Electronic Engineering from Sogang University, Seoul, in 1991 and 1993, and Ph.D. degree from the School of Electrical Engineering and Computer Science, Seoul National University in 2003. In 1993, he joined Electronics and Telecommunications Research Institute and worked

as a senior member of research staff in the Satellite Communications Division and Digital Broadcasting Research Division. He was one of key members in developing MMIC LNA and SSPA for the 20/30 GHz satellite transponder in ETRI. Since March 2005, he has been with the Department of Electrical and Communication Engineering, Soonchunhyang University in Korea as a faculty member. His research interests include design of the passive and active circuits for RF/microwave and millimeter-wave with MIC/MMIC technology, high frequency power amplifiers, application of periodic structure to the RF/microwave circuits and modeling of passive structure having periodic structures.

# Young-Bae Jung



was born in Seoul, Korea. He received the B.S. in radio science and engineering from KwangWoon University, Seoul, Korea, in 1999, the M.S. and the Ph.D degree in information and communications engineering from Korea Advanced Institute of Science and Technology (KAIST), Daejeon, Korea, in 2001 and 2009, respectively.

From 2001 to 2011, he was with Electronics and Telecommunications Research Institute (ETRI), Daejeon, Korea, as a senior researcher. From March 2011, he is a professor of the division of electric, electronic and control engineering, Hanbat National University, Daejeon, Korea. His work is focused on the active phased array antenna systems and next generation mobile base-station antennas. His research interests include active phased array antenna systems and active/passive components in the field of RF and Microwave.